

Supporting Information

Anisotropic charge transfer and gate tuning for p-SnS/n-MoS₂ vertical van der Waals diodes

Hui Yuan,^a Ruihan Xu,^a Jiale Ren,^a Jieli Yang,^a Shouyang Wang,^a Dongwen Tian,^a Yingshuang Fu,^b Quan Li,^{*c} Xiaoniu Peng^a and Xina Wang^{*a}

^a*School of Physics and Hubei Key Laboratory of Ferro & Piezoelectric Materials and Devices, Hubei University, Wuhan, 430062, China.*

Email: xnwang2006@hotmail.com

^b*School of Physics and Wuhan National High Magnetic Field Center, Huazhong University of Science and Technology, Wuhan, 430074, China.*

^c*Department of Physics, The Chinese University of Hong Kong, Shatin, Hong Kong, China.*

Email: liquan@phy.cuhk.edu.hk